

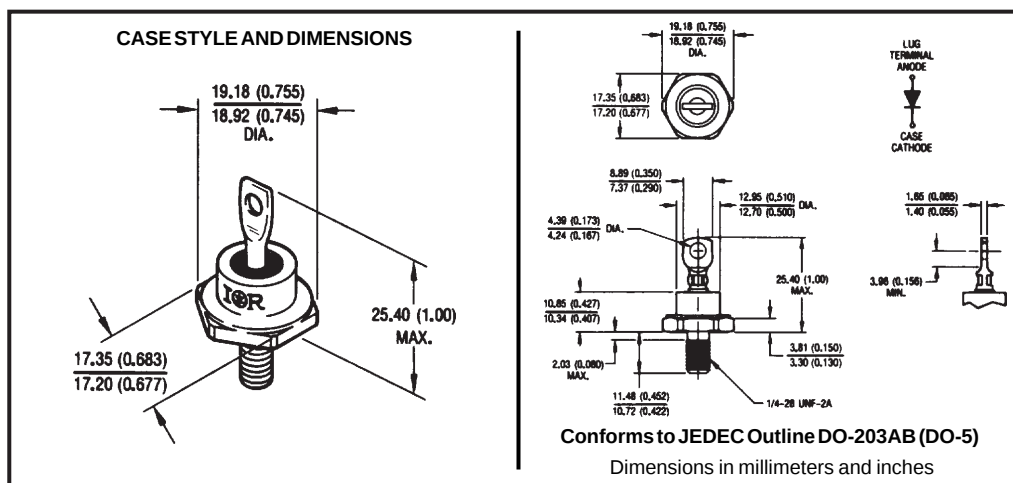
Major Ratings and Characteristics

Characteristics	95HQ015	Units
$I_{F(AV)}$ Rectangular waveform	95	A
V_{RRM}	15	V
I_{FSM} @ $t_p = 5 \mu s$ sine	7500	A
V_F @ 95 Apk, $T_J = 75^\circ C$	0.39	V
T_J range	-65 to 100	$^\circ C$

Description/Features

The 95HQ015 Schottky rectifier has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to $100^\circ C$ junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

- $100^\circ C$ T_J operation
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Hermetic package



Voltage Ratings

Part number	95HQ015
V_R Max. DC Reverse Voltage (V)	15
V_{RWM} Max. Working Peak Reverse Voltage (V)	25

Absolute Maximum Ratings

Parameters	95HQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	95	A	50% duty cycle @ $T_C = 44^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	7500	A	5 μs Sine or 3 μs Rect. pulse
	1200		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	9	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 2$ Amps, $L = 4.5$ mH
I_{AR} Repetitive Avalanche Current	2	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 3 \times V_R$ typical

Electrical Specifications

Parameters	95HQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.46	V	@ 95A
	0.62	V	@ 190A
	0.39	V	@ 95A
	0.55	V	@ 190A
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	20	mA	$T_J = 25^\circ\text{C}$
	1000	mA	$T_J = 100^\circ\text{C}$
	890	mA	$T_J = 100^\circ\text{C}$
	540	mA	$T_J = 100^\circ\text{C}$
C_T Max. Junction Capacitance	3600	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	7.5	nH	Measured from top of terminal to mounting plane
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	95HQ	Units	Conditions
T_J Max. Junction Temperature Range	-65 to 100	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-65 to 100	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	0.83	$^\circ\text{C/W}$	DC operation * See Fig. 4
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.25	$^\circ\text{C/W}$	Mounting surface, smooth and greased
wt Approximate Weight	15(0.53)	g(oz.)	
T Mounting Torque	Min. 23(20)	Kg-cm (lbf-in)	Non-lubricated threads
	Max. 46(40)		
Case Style	DO-203AB(DO-5)		JEDEC

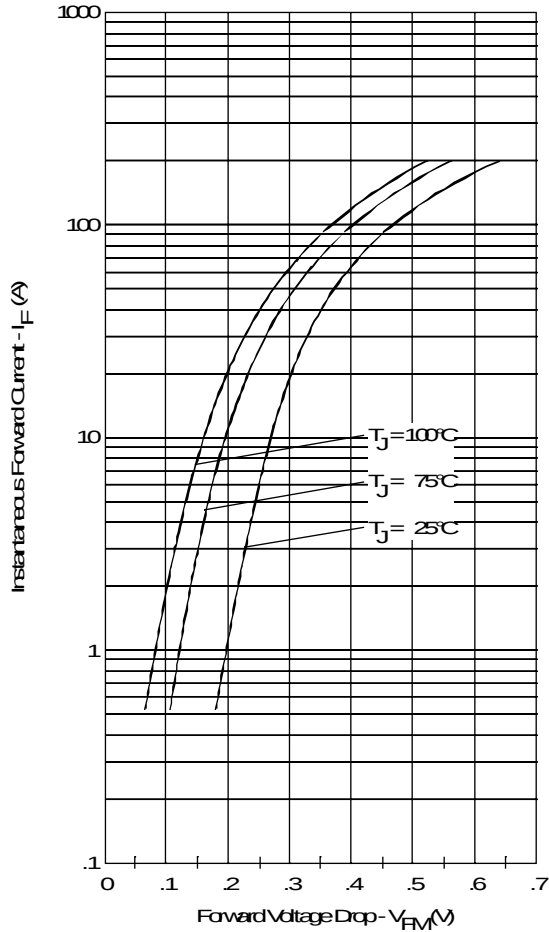


Fig. 1 - Maximum Forward Voltage Drop Characteristics

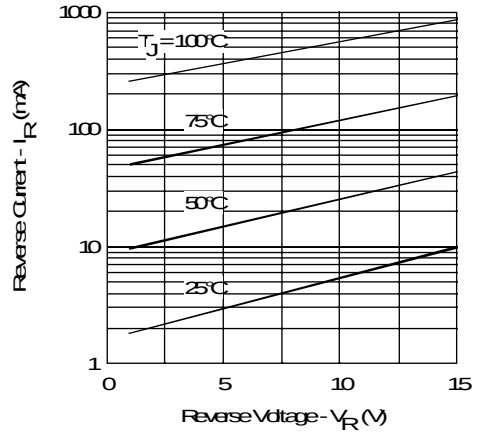


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

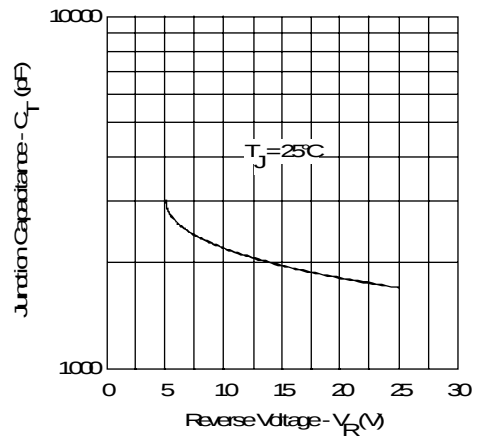


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

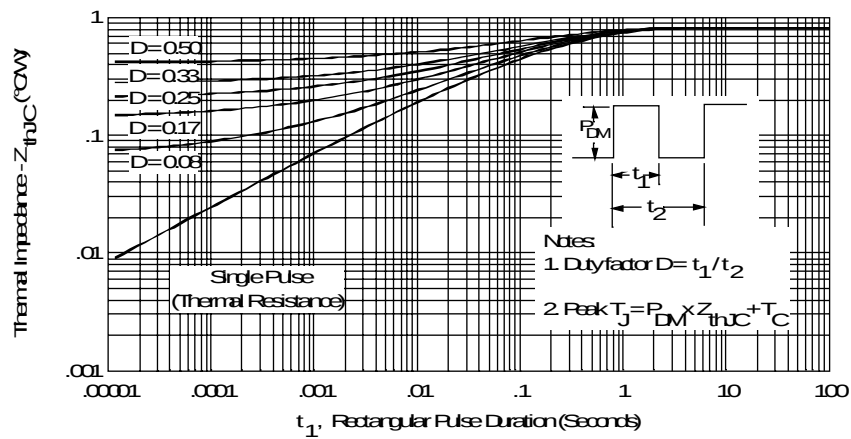


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

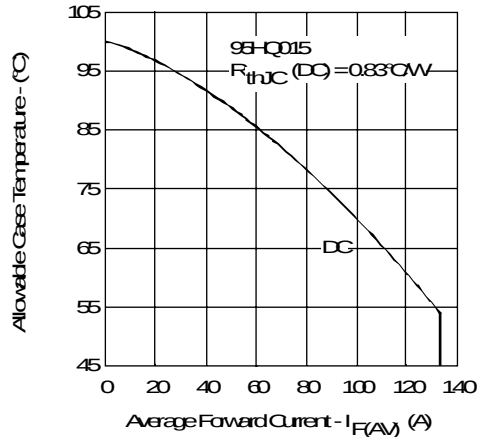


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

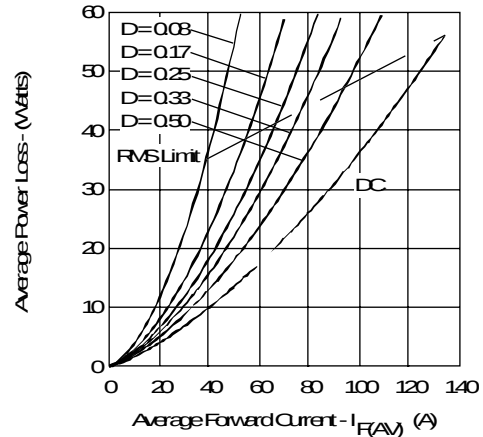


Fig. 6 - Forward Power Loss Characteristics

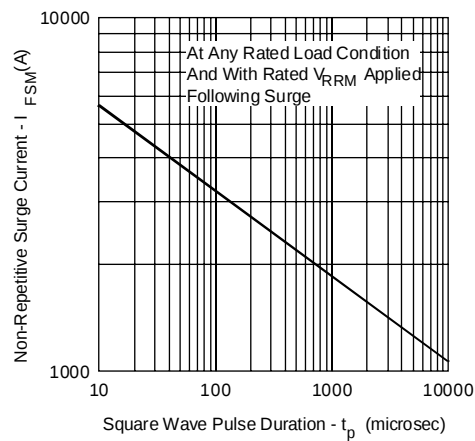


Fig. 7 - Maximum Non-Repetitive Surge Current

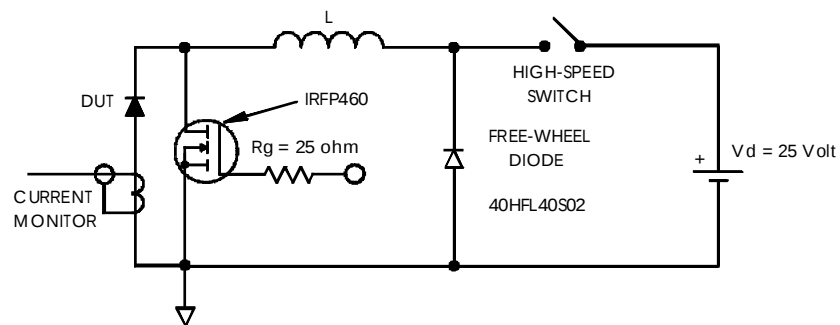


Fig. 8 - Unclamped Inductive Test Circuit